600V Half-Bridge Driver

PRODUCT SUMMARY

- **V_{OFFSET}** 600 V max.
- **I_O+/-** 130 mA/270 mA
- **V_{OUT}** 10 V - 20 V
- **$t_{on/off}$ (typ.)** 680 ns/150 ns
- **Deadtime (typ.)** 520 ns

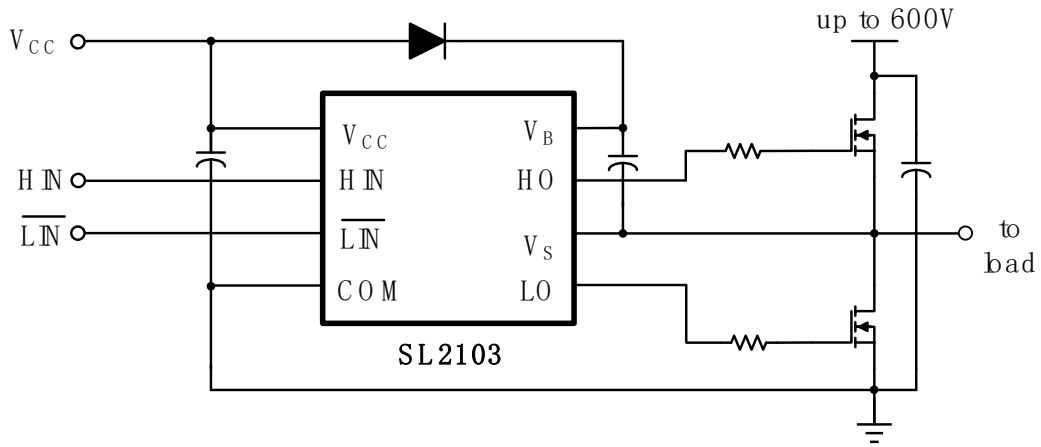
GENERAL DESCRIPTION

The SL2103 is a high voltage, high speed power MOSFET and IGBT drivers with dependent high- and low-side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output, down to 3.3 V logic. The output drivers feature a high pulse current buffer stage designed for minimum driver cross conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high-side configuration which operates up to 600 V.

FEATURES

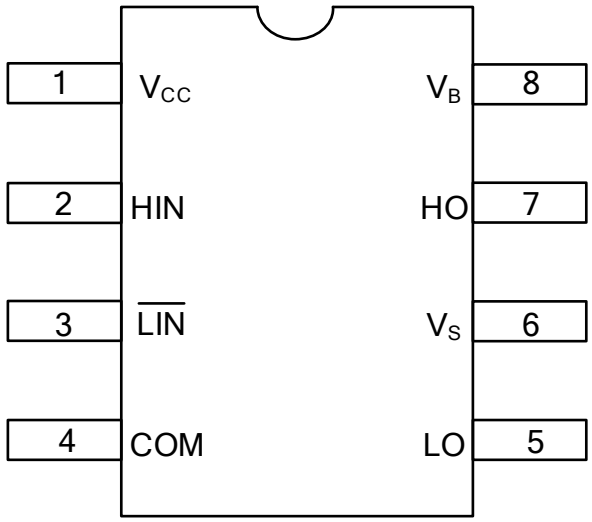
- Floating channel designed for bootstrap operation
- Fully operational to +600 V
- Tolerant to negative transient voltage, dV/dt immune
- Gate drive supply range from 10 V to 20 V
- Undervoltage lockout
- 3.3 V, 5 V, and 15 V logic compatible
- Cross-conduction prevention logic
- Matched propagation delay for both channels
- Internal set deadtime
- High-side output in phase with HIN input
- Low-side output out of phase with $\overline{\text{LIN}}$ input
- RoHS compliant
- SOP8 package

TYPICAL APPLICATION CIRCUIT



Refer to Pin Configuration for correct configuration. This diagram shows electrical connections only.

PIN CONFIGURATION

Package	Pin Configuration (Top View)
SOP8	

PIN DESCRIPTION

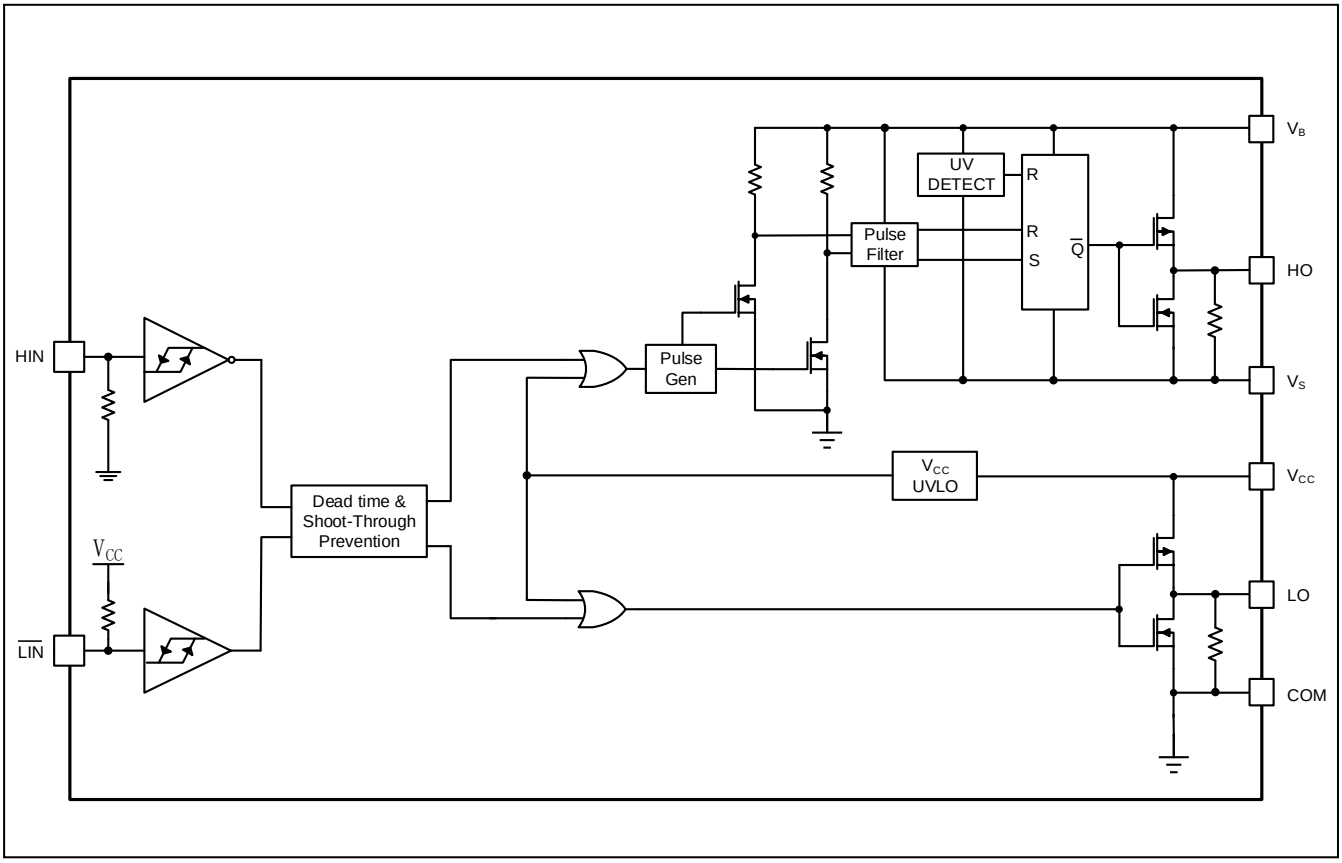
No.	Pin	Description
1	V_{CC}	Low-side and logic fixed supply
2	HIN	Logic input for high-side gate driver output (HO), in phase
3	$\overline{LIN}$	Logic input for low-side gate driver output (LO), out of phase
4	COM	Low-side return
5	LO	Low-side gate drive output
6	V_S	High-side floating supply return
7	HO	High-side gate drive output
8	V_B	High-side floating supply

ORDERING INFORMATION

Industrial Range: -40°C to +125°C

Order Part No.	Package	QTY
SL2103	SOP8, Pb-Free	2500/Reel

FUNCTIONAL BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Definition	Min.	Max.	Units
V_B	High-side floating absolute voltage	-0.3	625	V
V_S	High-side floating supply offset voltage	V_B - 25	V_B + 0.3	
V_{HO}	High-side floating output voltage	V_S - 0.3	V_B + 0.3	
V_{CC}	Low-side and logic fixed supply voltage	-0.3	25	
V_{LO}	Low-side output voltage	-0.3	V_{CC} + 0.3	
V_{IN}	Logic input voltage (HIN & $\overline{LIN}$)	-0.3	V_{CC} + 0.3	
dV_S/dt	Allowable offset supply voltage transient	---	50	V/ns
P_D	Package power dissipation @ $T_A \leqslant +25°C$	---	0.625	W
θ_{JA}	Thermal resistance, junction to ambient	---	200	°C/W
T_J	Junction temperature	---	150	°C
T_S	Storage temperature	-55	150	
T_L	Lead temperature (soldering, 10 seconds)	---	300	

Note: Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

RECOMMENDED OPERATION CONDITIONS

Symbol	Definition	Min.	Max.	Units
V_B	High-side floating absolute voltage	V_S + 10	V_S + 20	V
V_S	High-side floating supply offset voltage		600	
V_{HO}	High-side floating output voltage	V_S	V_B	
V_{CC}	Low-side and logic fixed supply voltage	10	20	
V_{LO}	Low-side output voltage	0	V_{CC}	
V_{IN}	Logic input voltage (HIN & $\overline{LIN}$)	0	V_{CC}	
T_A	Ambient temperature	- 40	125	°C

Note: The input/output logic timing diagram is shown in Figure 1. For proper operation the device should be used within the recommended conditions. The V_S offset rating is tested with all supplies biased at a 15 V differential.

DYNAMIC ELECTRICAL CHARACTERISTICS

V_{BIAS} (V_{CC}, V_{BS}) = 15 V, C_L = 1000 pF and T_A = 25°C unless otherwise specified.

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
t_{on}	Turn-on propagation delay	V_S = 0 V	---	680	820	ns
t_{off}	Turn-off propagation delay	V_S =0 V	---	150	220	
t_r	Turn-on rise time		---	70	170	
t_f	Turn-off fall time		---	35	90	
DT	Deadtime, LS turn-off to HS turn-on & HS turn-on to LS turn-off		400	520	750	
MT	Delay matching, HS & LS turn-on/off		---	---	60	

STATIC ELECTRICAL CHARACTERISTICS

V_{BIAS} (V_{CC}, V_{BS}) = 15 V and T_A = 25°C unless otherwise specified. The V_{IN}, V_{TH}, and I_{IN} parameters are referenced to COM. The V_O and I_O parameters are referenced to COM and are applicable to the respective output leads: HO or LO.

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
V_{IH}	Logic “1” (HIN) & Logic “0” ($\overline{LIN}$) input voltage	V_{CC} = 10 V to 20V	2.5	---	---	V
V_{IL}	Logic “0” (HIN) & Logic “1” ($\overline{LIN}$) input voltage		---	---	0.8	
V_{OH}	High level output voltage, V_{BIAS} - V_O	I_O = 2 mA	---	0.05	0.2	
V_{OL}	Low level output voltage, V_O		---	0.02	0.1	
I_{LK}	Offset supply leakage current	V_B = V_S = 600 V	---	---	50	µA
I_{QBS}	Quiescent V_{BS} supply current	V_{IN} = 0 V	---	60	75	
I_{QCC}	Quiescent V_{CC} supply current		---	220	280	
I_{IN+}	Logic “1” input bias current	HIN = 5 V, $\overline{LIN}$ = 0 V	---	8	15	
I_{IN-}	Logic “0” input bias current	HIN = 0 V, $\overline{LIN}$ = 5 V	---	---	5	
V_{CCUV+} V_{BSUV+}	V_{CC} and V_{BS} supply undervoltage positive going threshold		8	8.9	9.8	V
V_{CCUV-} V_{BSUV-}	V_{CC} and V_{BS} supply undervoltage negative going threshold		7.4	8.2	9	

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
I_{O+}	Output high short circuit pulsed current	V_O = 0 V, V_{IN} = V_{IH} PW ⩽ 10 μs	130	290		mA
I_{O-}	Output low short circuit pulsed current	V_O = 15 V, V_{IN} = V_{IL} PW ⩽ 10 μs	270	600		

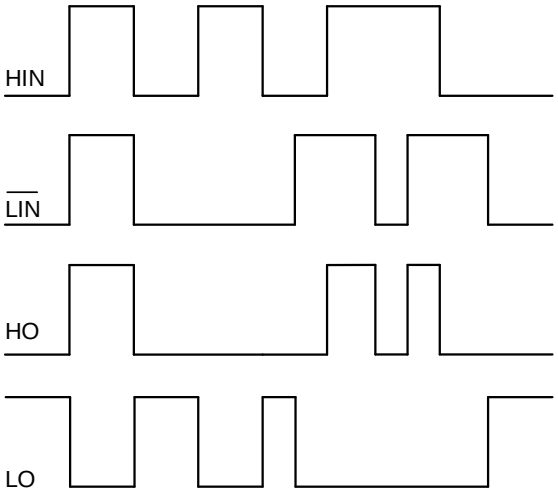


Figure 1. Input/Output Timing Diagram

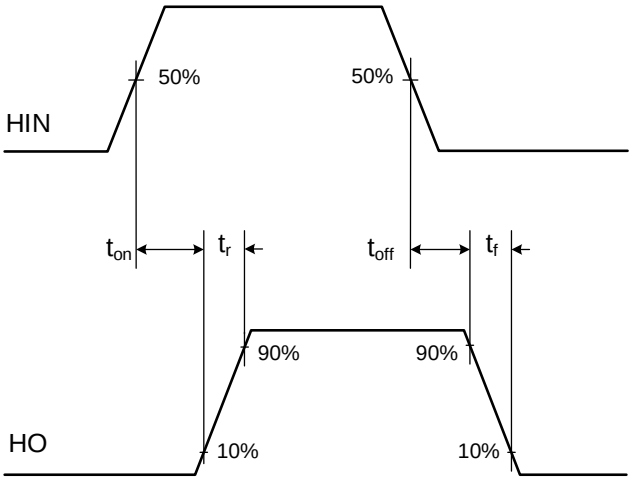


Figure 2. High Side Switching Time Waveform

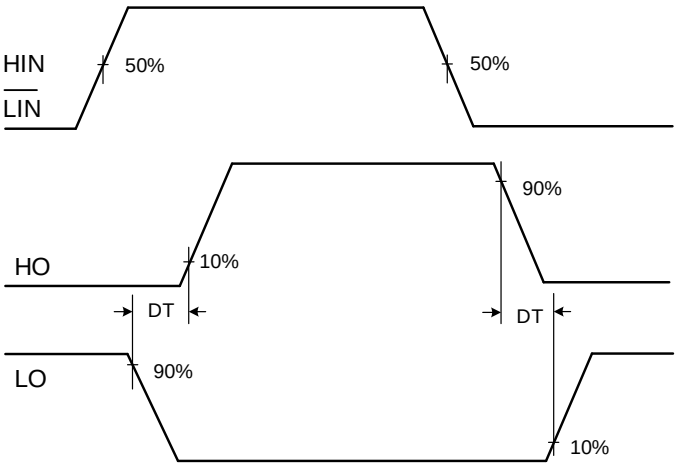


Figure 3. Dead Time Waveform

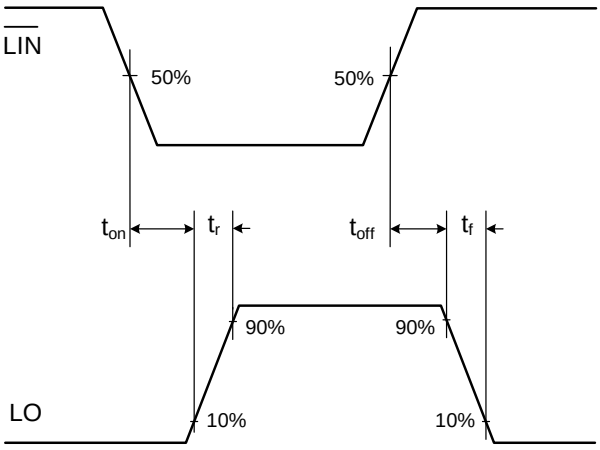
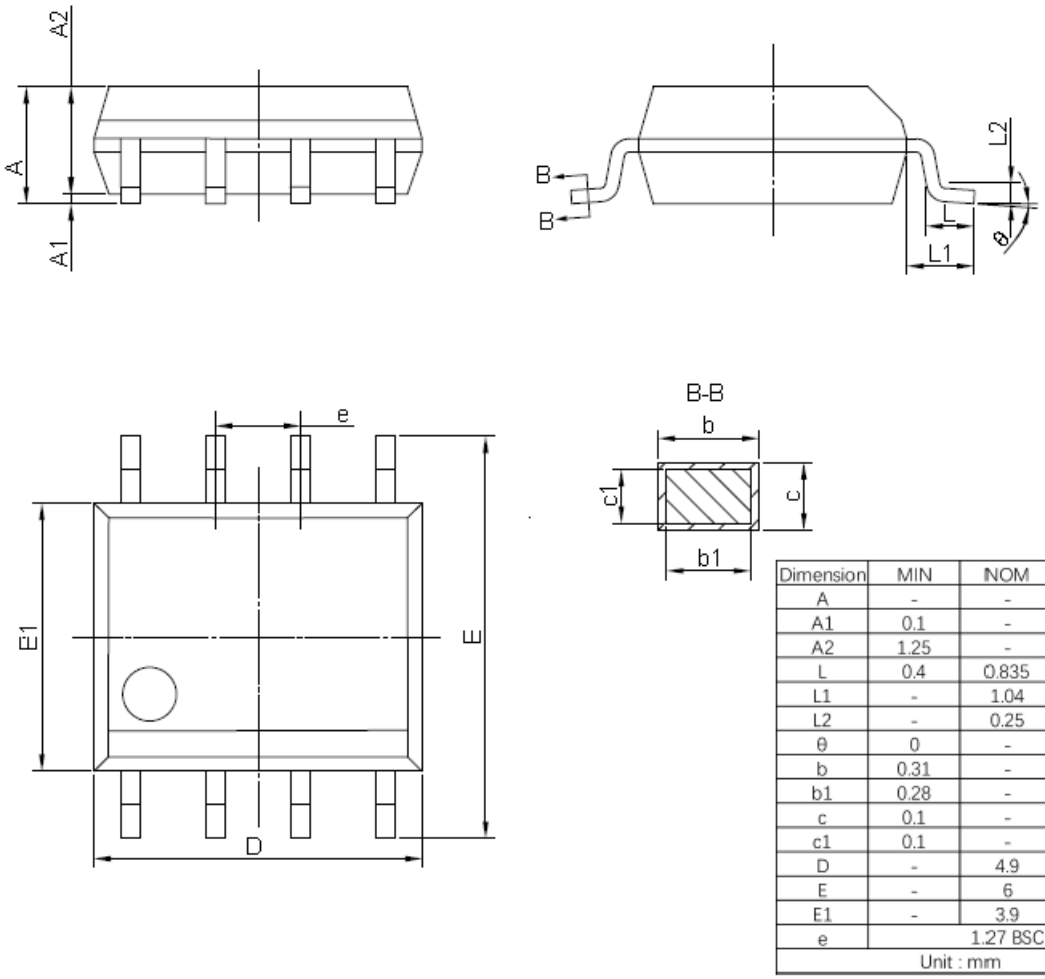


Figure 4. Low Side Switching Time Waveform

PACKAGE CASE OUTLINES



Dimension	MIN	NOM	MAX
A	-	-	1.75
A1	0.1	-	0.25
A2	1.25	-	-
L	0.4	0.835	1.27
L1	-	1.04	-
L2	-	0.25	-
θ	0	-	8
b	0.31	-	0.51
b1	0.28	-	0.48
c	0.1	-	0.25
c1	0.1	-	0.25
D	-	4.9	-
E	-	6	-
E1	-	3.9	-
e	1.27 BSC		
Unit : mm			

Figure 5. SOP8 Outline Dimensions